

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China









SINGLE LOW VOLTAGE RAIL-TO-RAIL **OUTPUT OPERATIONAL AMPLIFIER**

Description

The AZV321 is single low voltage (2.7V to 5.5V) operational amplifier which has rail-to-rail output swing capability. The input common-mode voltage range includes ground. The chip exhibits excellent speedpower ratio, achieving 1MHz of bandwidth and 1V/µs of slew rate with low supply current.

The AZV321 is built with BiCMOS process. It has bipolar input and output stages for improved noise performance, low input offset and higher output current drive.

The AZV321 is available in the package of SC-70-5, which is approximately half the size of SOT-23-5. The small package saves space on pc boards, and enables the design of small portable electronic devices. It also allows the designer to place the device closer to the signal source to reduce noise pickup and increase signal integrity.

The AZV321 is also available in standard SOT-23-5 package.

Features (For V_{CC} =5V and V_{EE} =0V, Typical unless Otherwise Noted)

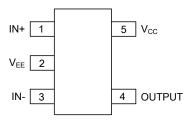
- Guaranteed 2.7V to 5.5V Performance
- No Crossover Distortion
- Gain-Bandwidth Product 1MHz
- Industrial Temperature Range: -40°C to +85°C
- Low Supply Current: 130µA
- Rail-to-Rail Output Swing under 10kΩ Load:

V_{OH} up to V_{CC}-10mV V_{OL} near to V_{EE} +65mV

 V_{CM} : -0.1V to V_{CC} -0.8V

Pin Assignments

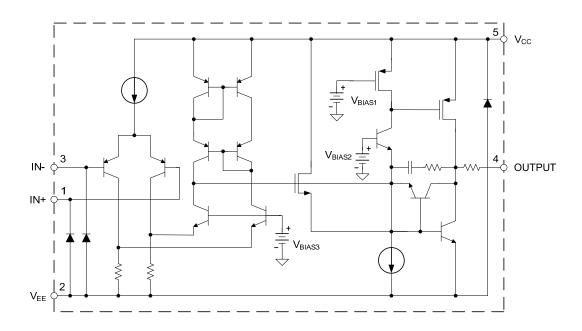
KS/K Package (SC-70-5/SOT-23-5)



Applications

- Active Filters
- Low Power, Low Voltage Applications
- General Purpose Portable Devices
- Cellular Phone, Cordless Phone
- Battery-Powered Systems

Functional Block Diagram







AZV321

Absolute Maximum Ratings (Note 1)

Symbol	Parameter	Rating	Unit
V _{CC}	Power Supply Voltage	6	٧
T _J	Operation Junction Temperature	150	°C
T _{STG}	Storage Temperature Range	-65 to 150	°C
T _{LEAD}	Lead Temperature (Soldering, 10 Seconds)	260	°C
	ESD (Machine Model)	200	V
	ESD (Human Body Model)	2000	V

Note 1: Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "Recommended Operating Conditions" is not implied. Exposure to "Absolute Maximum Ratings" for extended periods may affect device reliability.

Recommended Operating Conditions

Symbol	Parameter	Min	Max	Unit
V _{CC}	Supply Voltage	2.7	5.5	V
T _A	Ambient Operating Temperature Range	-40	85	°C





AZV321

Electrical Characteristics

AZV321-2.7V Electrical Characteristics (All limits are guaranteed for T_A =25°C, V_{CC} =2.7V, V_{EE} =0V, V_{CM} =1.0V, V_O = V_{CC} /2 and R_L >1M Ω , limits in **bold types** are guaranteed for T_A =-40°C to 85°C, unless otherwise specified. Note 2)

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V	Input Offset Voltage			1.7	7	mV
V _{IO}	Input Offset Voltage			1.7 1.7 1.7 1.7 5 -0.1 80 50 65 50 60 5 20 10 30 2.60 2.69	9	
	January Dies Comment			11	250	^
I _B	Input Bias Current	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	500	nA		
	Input Offset Current			5	50	nA
I _{IO}	Input Offset Current		1.7 1.7 1.7 1.7 5 -0.1 80 50 65 50 60 5 20 10 30 2.60 2.69 60 1	150	IIA	
V _{CM}	Input Common Mode Voltage Range	for CMRR≥50dB	-0.1		1.9	V
,	Community Community	\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \		80	170	
I _{CC}	Supply Current	Vo=Vcc/2, AvcL=1, 110 load	50 65 50 60	270	μA	
CMRR	Common Mode Rejection Ratio	0≤V _{CM} ≤1.7V	50	65		dB
PSRR	Power Supply Rejection Ratio	2.7V≤V _{CC} ≤5V, V _O =1V	50	60		dB
I _{SOURCE}	Outside Object Circuit Courset	V _O =0V	5	20		mA
I _{SINK}	Output Short Circuit Current	V _O =2.7V	10	30		mA
V _{OH}	Outrot Valta na Outra	D 401-0 t- 4.05\/	2.60	2.69		V
V _{OL}	Output Voltage Swing	KL-10K17 (0 1.35V		60	180	mV
GBWP	Gain Bandwidth Product	C _L =200pF		1		MHz
фм	Phase Margin			60		Deg
G _M	Gain Margin			10		dB

Note 2: Limits over the full temperature are guaranteed by design, but not tested in production.



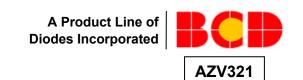
Electrical Characteristics (Cont.)

AZV321-5V Electrical Characteristics (All limits are guaranteed for T_A =25°C, V_{CC} =5V, V_{EE} =0V, V_{CM} =2.0V, V_O = V_{CC} /2 and R_L >1M Ω , limits in **bold types** are guaranteed for T_A =-40°C to 85°C, unless otherwise specified. Note 2)

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
1/	land Official Voltage			1.7	7	
V_{IO}	input Offset voltage				9	mV
1	Input Dice Current			11	250	η.Λ
l _Β	input bias current		1.7 11 5 -0.1 84 100 80 50 65 50 60 10 160 4.7 4.96 4.6 4.9 4.99 4.8 120 65 1 1 1 60	500	nA	
I _{IO}	Input Offset Current			1.7 11 5 -0.1 130 84 100 80 50 65 50 60 10 160 4.7 4.96 4.6 4.9 4.99 4.8 120 65 1 1	50	nA
10			1.7 11 5 -0.1 130 84 100 80 50 65 50 60 10 160 4.7 4.96 4.6 4.9 4.99 4.8 120 65 1 1 1 60	150	ПА	
V_{CM}	Input Common Mode Voltage Range	for CMRR≥50dB	-0.1		4.2	V
laa	Supply Current	_\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\	1.7 11 5 -0.1 130 84 100 80 50 65 7 50 60 10 160 4.7 4.96 4.6 4.9 4.99 4.8 120 65	130	250	
Icc	Supply Current	V0-VCC/2, AVCL-1, 110 10au			350	μA
Gv	Larga Signal Valtaga Cain	B. =3kQ	1.7 11 5 -0.1 84 100 80 50 65 =1V 50 60 10 160 4.7 4.96 4.6 4.9 4.99 4.8 120 65 1 1 1 60	100		dВ
9	Large Signal Voltage Gain	KL-2K11			dB	
CMRR	Common Mode Rejection Ratio	0≤V _{CM} ≤4V	50	65		dB
PSRR	Power Supply Rejection Ratio	2.7V≤V _{CC} ≤5V, V _O =1V, V _{CM} =1V	50	60		dB
Isource	Output Short Circuit Current	V _O =0V	5	60		mA
I _{SINK}	Output Short Circuit Current	V _O =5V	10	160		mA
	PSRR Power Supply Rejection Ratio 2.7V≤V _{CC} ≤5V, V _O =1V, V _{CM} =1V V _O =0V Output Short Circuit Current	4.7	4.96			
V		N2N12 to 2:5V	4.6			V
VOH		B =10k0 to 2.5V	4.9	4.99		
	Output Voltage Swing	N10K22 (0 2.5V	4.8			
	Output Voltage Owing	P. =2k0 to 2.5\/	-0.1 84 80 50 50 4.7 4.6 4.9 4.8	120	300	
V_{OL}		N2N12 to 2.5V			400	mV
V OL	Input Offset Voltage 11 Input Bias Current 5 Input Common Mode Voltage Range for CMRR≥50dB -0.1 Supply Current Vo=Vcc/2, Avcl=1, no load 130 Large Signal Voltage Gain RL=2kΩ 84 100 Common Mode Rejection Ratio 0≤VcM≤4V 50 65 Power Supply Rejection Ratio 2.7V≤Vcc≤5V, Vo=1V, VcM=1V 50 60 Output Short Circuit Current Vo=0V 5 60 Vo=5V 10 160 RL=2kΩ to 2.5V 4.7 4.96 4.6 4.9 4.99 RL=10kΩ to 2.5V 65 65 RL=10kΩ to 2.5V 65 65 Slew Rate 1 1 Gain Bandwidth Product CL=200pF 1 Phase Margin 60	65	180	mv		
		1410/32 to 2.0 V		111 5 -0.1 130 84 100 80 50 65 50 60 10 160 4.7 4.96 4.6 4.9 4.9 4.8 120 65 1 1 1 60	280	
SR	Slew Rate			1		V/µS
GBWP	Gain Bandwidth Product	C _L =200pF		1		MHz
φм	Phase Margin			60		Deg
G_M	Gain Margin			10		dB

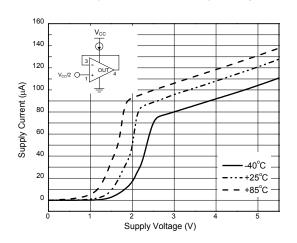
Note 2: Limits over the full temperature are guaranteed by design, but not tested in production.



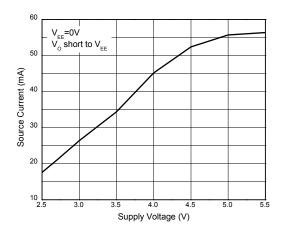


Performance Characteristics

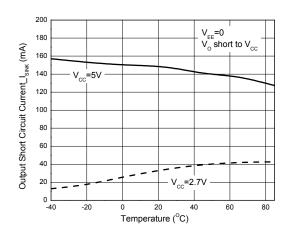
Supply Current vs. Supply Voltage



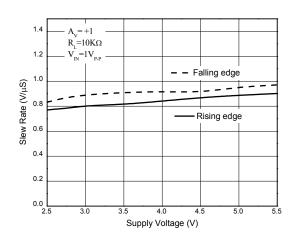
Output Source Current vs. Supply Voltage



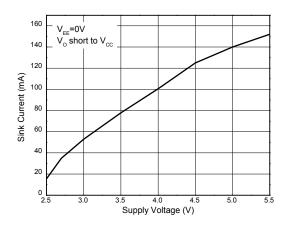
Short Circuit Current $_{I_{SINK}}$ vs. Temperature



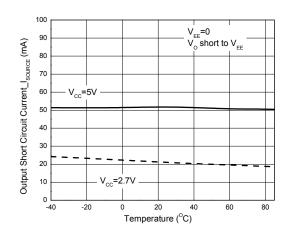
Slew Rate vs. Supply Voltage



Output Sink Current vs. Supply Voltage



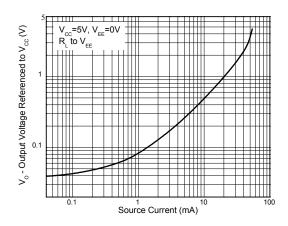
Short Circuit Current_I_{SOURCE} vs. Temperature



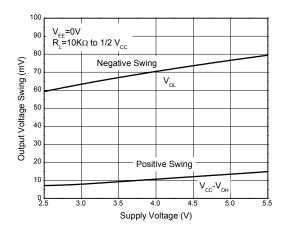


Performance Characteristics (Cont.)

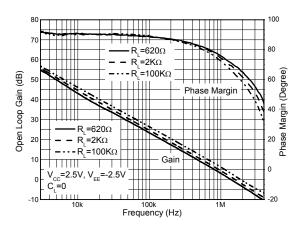
Output Voltage vs. Source Current



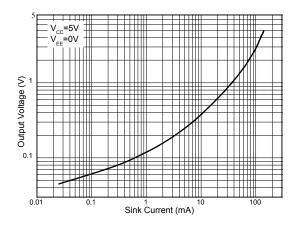
Output Voltage Swing vs. Supply Voltage



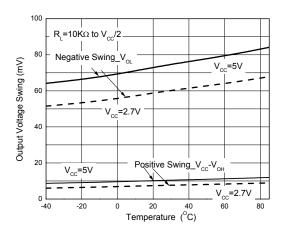
Gain and Phase vs. Frequency and Resistive Load



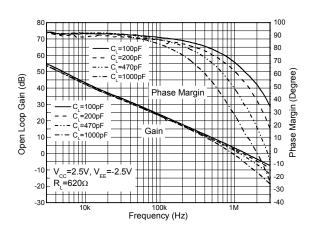
Output Voltage vs. Sink Current



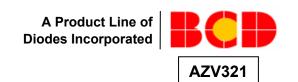
Output Voltage Swing vs. Temperature



Gain and Phase vs.
Frequency and Capacitive Load

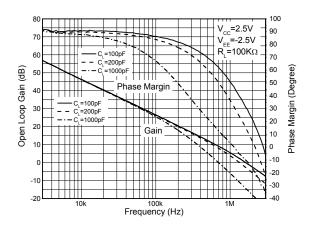




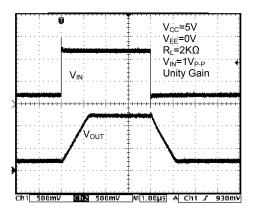


Performance Characteristics (Cont.)

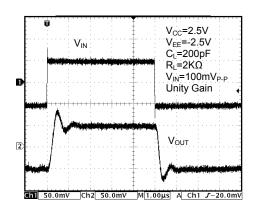
Gain and Phase vs. Frequency and Capacitive Load



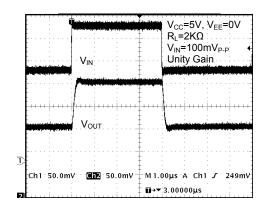
Non-Inverting Input Large Signal Pulse Response



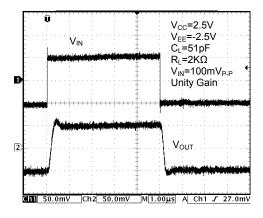
Output with Excessive Capacitive Load



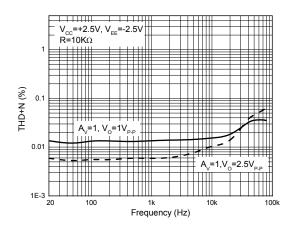
Non-Inverting Input Small Signal Pulse Response



Output with Excessive Capacitive Load

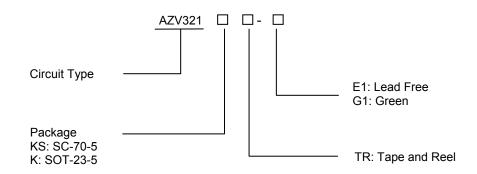


THD+N vs. Frequency





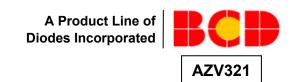
Ordering Information



Dooksass	Temperature	Part N	umber	Mark	ing ID	Dealing Tone
Package Range		Lead Free	Green	Lead Free	Green	Packing Type
SC-70-5	-40 to 85°C	AZV321KSTR-E1	AZV321KSTR-G1	21	B1	Tape & Reel
SOT-23-5		AZV321KTR-E1	AZV321KTR-G1	E6D	G6D	Tape & Reel

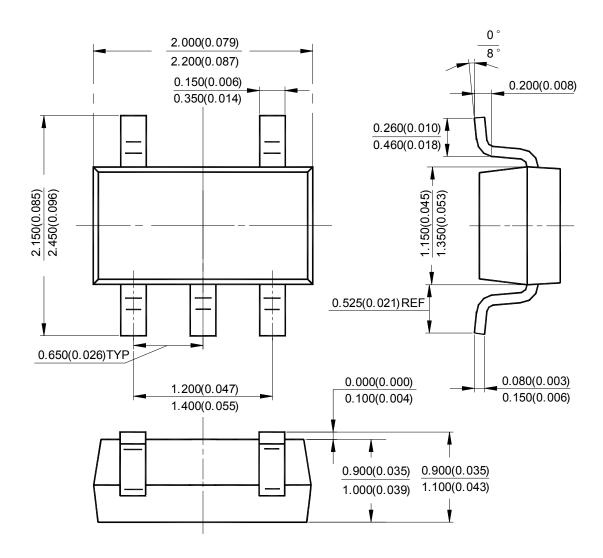
BCD Semiconductor's Pb-free products, as designated with "E1" suffix in the part number, are RoHS compliant. Products with "G1" suffix are available in green packages.





Package Outline Dimensions (All dimensions in mm(inch).)

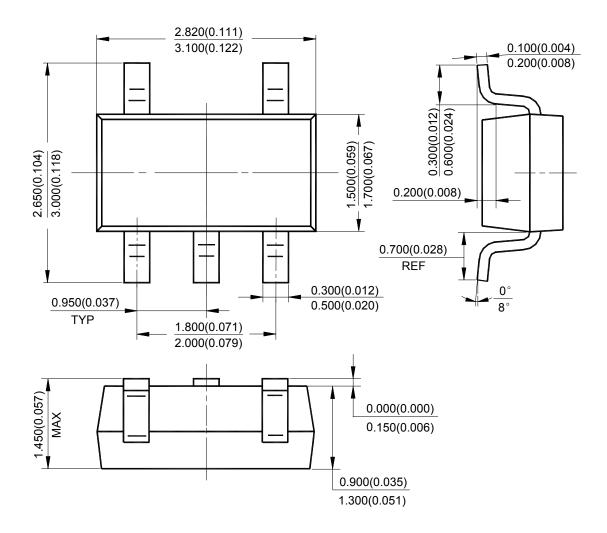
SC-70-5





Package Outline Dimensions (Cont. All dimensions in mm(inch).)

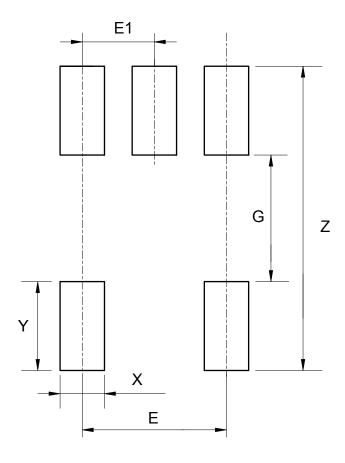
SOT-23-5





Suggested Pad Layout

SC-70-5

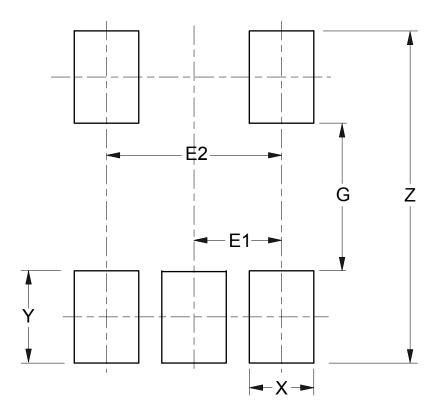


Dimensions	Z	G	X	Y	Е	E1
Dimensions	(mm)/(inch)	(mm)/(inch)	(mm)/(inch)	(mm)/(inch)	(mm)/(inch)	(mm)/(inch)
Value	2.740/0.108	1.140/0.045	0.400/0.016	0.800/0.031	1.300/0.051	0.650/0.026



Suggested Pad Layout (Cont.)

SOT-23-5



Dimensions	cione	Z	G	X	Y	E1	E2
	(mm)/(inch)	(mm)/(inch)	(mm)/(inch)	(mm)/(inch)	(mm)/(inch)	(mm)/(inch)	
Valı	ue	3.600/0.142	1.600/0.063	0.700/0.028	1.000/0.039	0.950/0.037	1.900/0.075



AZV321

IMPORTANT NOTICE

DIODES INCORPORATED MAKES NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY AND FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. Diodes Incorporated does not assume any liability arising out of the application or use of this document or any product described herein; neither does Diodes Incorporated convey any license under its patent or trademark rights, nor the rights of others. Any Customer or user of this document or products described herein in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on Diodes Incorporated website, harmless against all damages.

Diodes Incorporated does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel. Should Customers purchase or use Diodes Incorporated products for any unintended or unauthorized application, Customers shall indemnify and hold Diodes Incorporated and its representatives harmless against all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized application.

Products described herein may be covered by one or more United States, international or foreign patents pending. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks.

This document is written in English but may be translated into multiple languages for reference. Only the English version of this document is the final and determinative format released by Diodes Incorporated.

LIFE SUPPORT

Diodes Incorporated products are specifically not authorized for use as critical components in life support devices or systems without the express written approval of the Chief Executive Officer of Diodes Incorporated. As used herein:

- A. Life support devices or systems are devices or systems which:
 - 1. are intended to implant into the body, or
 - 2. support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in significant injury to the user.
- B. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or to affect its safety or effectiveness.

Customers represent that they have all necessary expertise in the safety and regulatory ramifications of their life support devices or systems, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of Diodes Incorporated products in such safety-critical, life support devices or systems, notwithstanding any devices- or systems-related information or support that may be provided by Diodes Incorporated. Further, Customers must fully indemnify Diodes Incorporated and its representatives against any damages arising out of the use of Diodes Incorporated products in such safety-critical, life support devices or systems.

Copyright © 2013, Diodes Incorporated

www.diodes.com